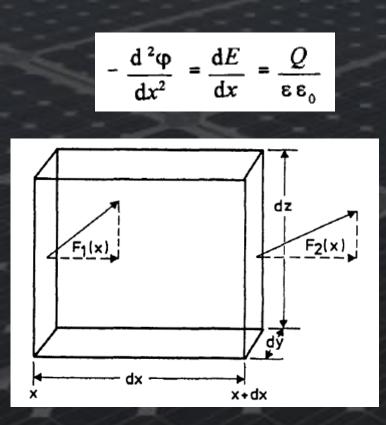
There are two mechanismos for charge transport

Electric field

Diffusion

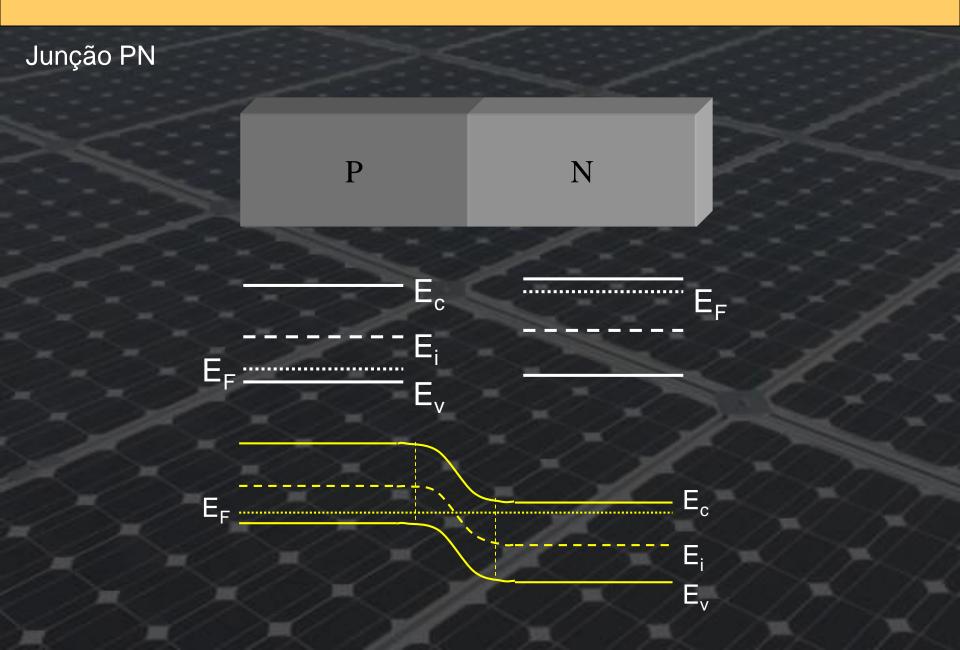
$$I_{n} = q \left(n \mu_{n} E + D_{n} \frac{\mathrm{d}n}{\mathrm{d}x} \right)$$

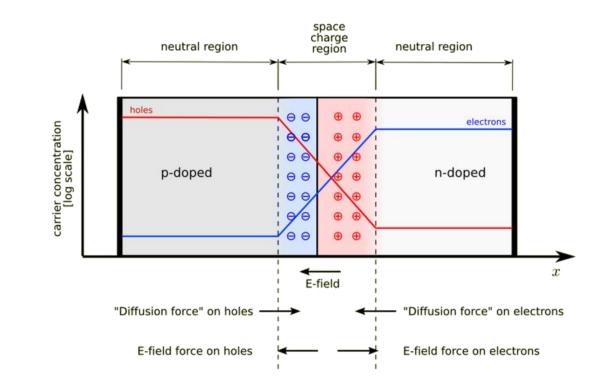


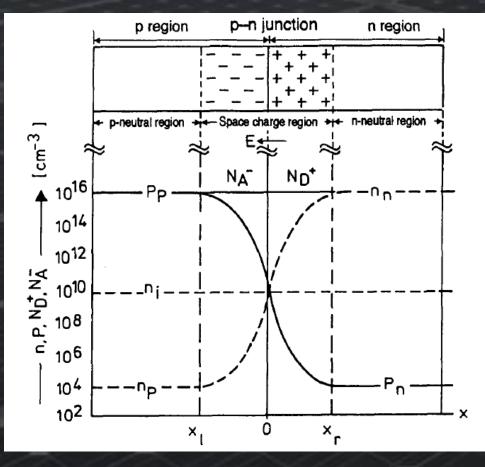
$$\frac{\mathrm{d}E}{\mathrm{d}x} = \frac{q}{\varepsilon\varepsilon_0} \left(p - n + N_\mathrm{D}^* - N_\mathrm{A}^* \right)$$

$$\Delta F = \frac{\mathrm{d}F(x)}{\mathrm{d}x} \, \delta x \, \mathrm{d}y \, \mathrm{d}z = (G - R)\delta x \, \mathrm{d}y \, \mathrm{d}z$$

$$\frac{1}{q} \frac{\mathrm{d}I_{\mathrm{n}}(x)}{\mathrm{d}x} = R - G$$







 $N_{\rm A}^{\star} \approx N_{\rm A} \approx p_{\rm p} \text{ and } N_{\rm D}^{\star} \approx N_{\rm D} \approx n_{\rm n}$

We assume that in this example $N_A = 10^{16}$ cm⁻³ and $N_D = 10^{16}$ cm⁻³

In thermal equilibrium we continue to have

$$np = n_i^2$$

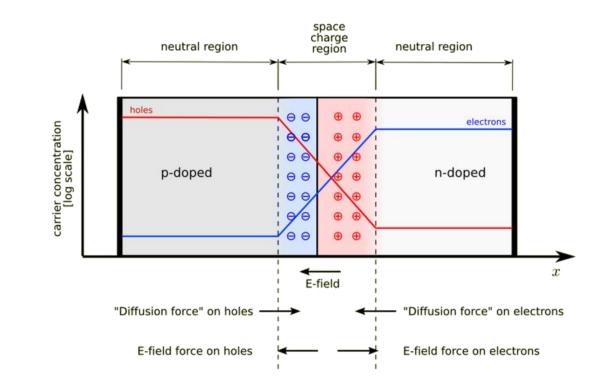
Therefore in the p neutral region $n_p = 10^4 \text{ cm}^{-3}$ and in the n region $p_n = 10^4 \text{ cm}^{-3}$

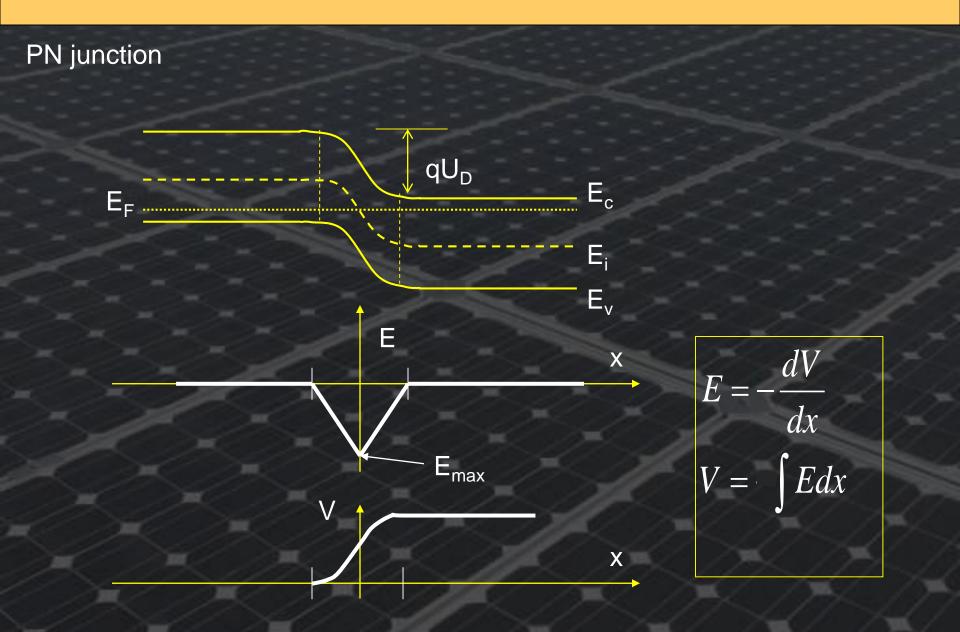
 $p_{\rm p}$ is the hole concentration in the p-neutral area, and $n_{\rm n}$ is the electron concentration in the n-neutral area.

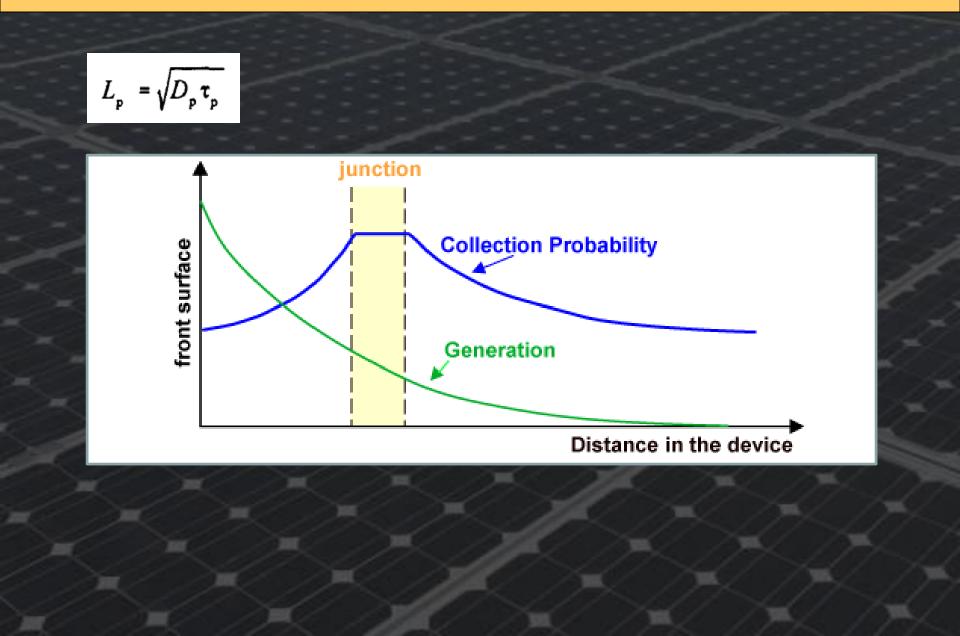
Since in some parts of the junction there is no charge neutrality, we must have an associated electric field

$$qn\mu_{n}E = -qD_{n}\frac{dn}{dx} \quad \text{Since In} = 0 \qquad E = -\frac{d\phi}{dx} \quad \text{E=-grad V}$$
$$D = \frac{kT}{q}\mu \quad \frac{d\phi}{dx} = \frac{kT}{q}\frac{dn}{n}\frac{1}{dx} \qquad \phi_{(x,r)} - \phi_{(x,l)} = -U_{T}\ln(n_{p}/n_{n}) = U_{D}$$

Since N_A = 10¹⁶ cm⁻³ and N_D = 10¹⁶ cm⁻³ we find U_D= 0.72 V for silicon at 300 K







Junção PN

Negligible voltage drop (ohmic contact) Negligible voltage drop (neutral region, high doping)

N

 V_0 (U_D-U)

Р

Ν

Most of the voltage applied appears across the depletion region

If we apply an external voltage UA

$$I_{\text{total}} = I_p + I_n$$

$$I_{\text{total}} = \left(\frac{q D_{n} n_{p0}}{L_{n}} + \frac{q D_{p} p_{n0}}{L_{p}}\right) (\exp(U_{A}/U_{T}) - 1)$$

$$p_{\rm n0} = n_{\rm i}^2 / N_{\rm D}$$
 resp. $n_{\rm p0} = n_{\rm i}^2 / N_{\rm A}$

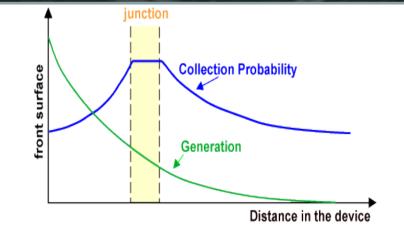
$$I_{o} = \left(\frac{q D_{n} n_{i}^{2}}{L_{n} N_{A}} + \frac{q D_{p} n_{i}^{2}}{L_{p} N_{D}}\right)$$

$$I = I_0 \left(\exp U_{\rm A} / U_{\rm T} - 1 \right)$$

If we have now some ilumination on the cell

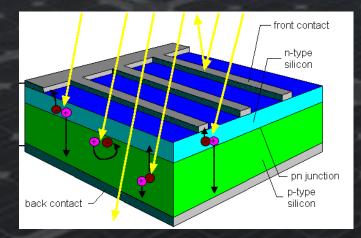
$$I = I_{0} \left(\exp \left[U/U_{T} \right] - I_{L} \right)$$





Solar cell I-V characteristics

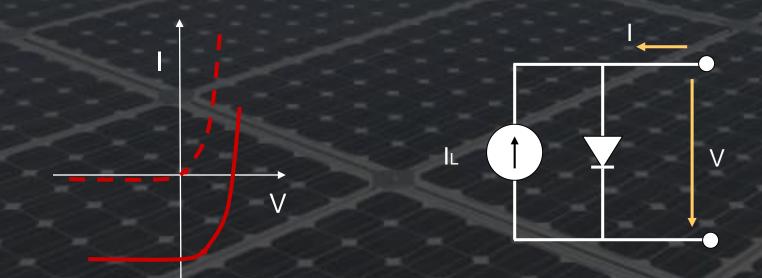
$$I = I_0(e^{qV/kT} - 1)$$



$$\ln I_{total} = \ln I_0 + \frac{q}{kT}V$$

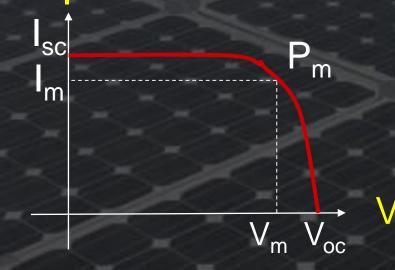
0

Characteristics under ilumination



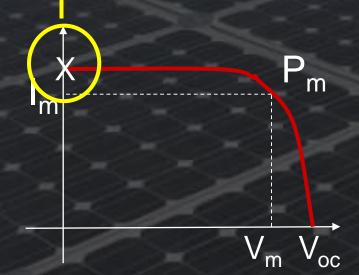
 $I_{total} = I_0 (e^{qV/kT} - 1) - I_L$

Important parameters



Solar cell parameters • V_{oc} - open circuit voltage, • Isc - short circuit current, • P_m - maximum power point • I_m , V_m – current and voltage at maximum power point • FF - Fill factor η – Efficiency R_s – series resistance • R_{sh} – shunt resistance

Short circuit current



• The short-circuit current is the current through the solar cell when the voltage across the solar cell is zero (i.e., when the solar cell is short circuited).

•The short-circuit current is due to the generation and collection of light-generated carriers.

• The short-circuit current is the largest current which may be drawn from the solar cell.

tota

Pm

 V_{m}

Open circuit voltage

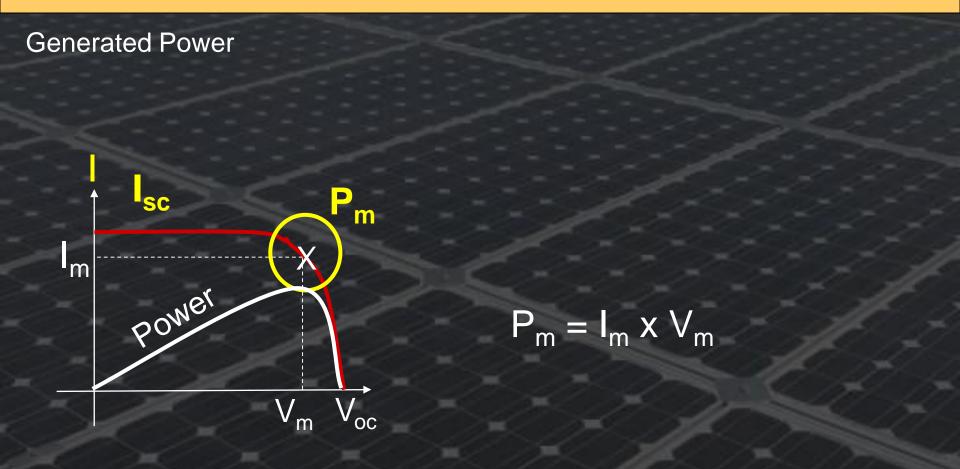
SC

l_m

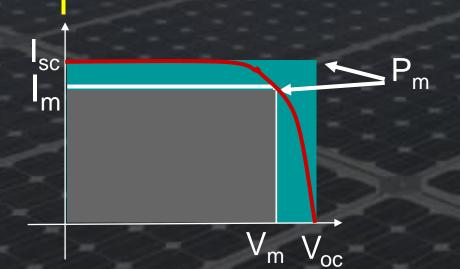
• The open-circuit voltage, V_{oc} , is the maximum voltage available from a solar cell, and this occurs at zero current.

0C

 $\frac{kT}{a}\ln(\frac{I_L}{I_0}+1)$



Fill factor

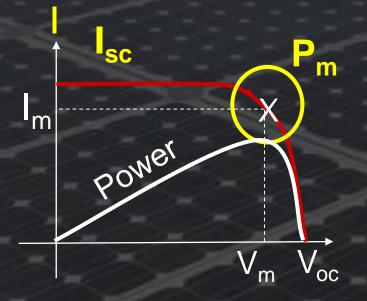


• The FF is defined as the ratio of the maximum power from the actual solar cell to the maximum power from a ideal solar cell

FF is a measure of the "squareness" of the solar cell

 $FF = \frac{Max \ power \ from \ real \ cell}{Max \ power \ from \ ideal \ cell} = \frac{V_m I_m}{V_{oc} I_{sc}}$

Conversion efficiency





• The efficiency is the most commonly used parameter to compare the performance of one solar cell to another.

• Efficiency of a cell also depends on the solar spectrum, intensity of sunlight and the temperature of the solar cell.

